

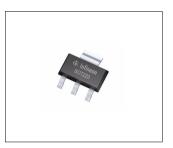
Voltage Regulator

Data Sheet



Features

- Output voltage 3.3 V or adjustable
- 1.0 A output current
- Low drop voltage < 1.2 V @ 800 mA
- Short circuit protected
- Overtemperature protected
- Operating range up to 15 V
- Industrial type
- Green Product (RoHS compliant)



For automotive and transportation applications, please refer to the Infineon TLE and TLF voltage regulator series.

Functional Description

The IFX1117 is a monolithic integrated fixed NPN type voltage regulator that can supply loads up to 1.0 A. The device is housed in the small surface mounted SOT223 package. The IC is equipped with additional protection against overload, short circuit and overtemperature.

The IFX1117ME V33 supplies a regulated output voltage of 3.3 V (±2%). The IFX1117ME V supplies an output voltage with ±2% precision adjustable via an external voltage divider. The input voltage for the IFX1117ME V33 ranges from 4.5 V (= V_Q+V_{DR}) to 15 V for a load current of 800 mA, for the maximum load current of 1.0 A a minimum input voltage of 4.7 V is required. The drop voltage V_{DR} ranges from 1.1 V to 1.4 V depending on the load current level.

The device operates in the temperature range of $T_i = 0$ to 125 °C.

Туре	Package	Marking
IFX1117ME V33	PG-SOT223	111733
IFX1117ME V	PG-SOT223	1117V



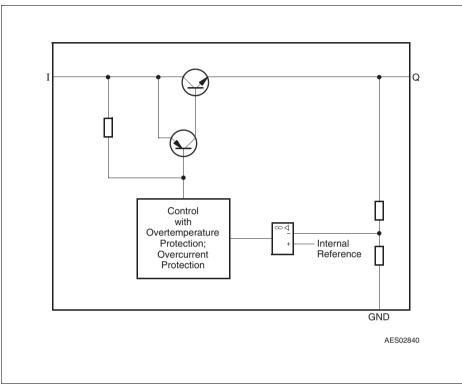


Figure 1 Block Diagram for Fixed Output Voltage IFX1117ME V33



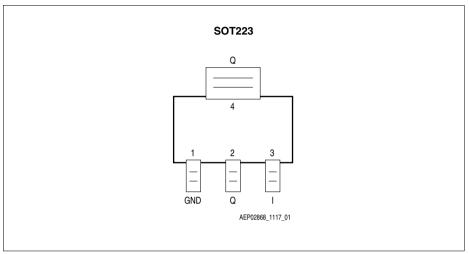


Figure 2 Pin Configuration IFX1117ME V33 (top view)

Table 1 Pin Definitions and Functions IFX1117ME V33

Pin No.	Symbol	Function
1	GND	Ground
2	Q	Output; Connect output pin to GND via a capacitor $C_{\rm Q} \ge 10 \ \mu\text{F}$ with ESR $\le 20 \ \Omega$ (see also graph "Region of Stability")
3	I	Input
4 (TAB)	Q	Output; Connect to pin 2 and heatsink area on PCB



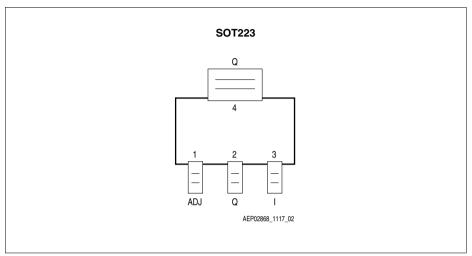


Figure 3 Pin Configuration IFX1117ME V (top view)

Table 2 Pin Definitions and Functions IFX1117ME V

Pin No.	Symbol	Function
1	ADJ	Adjust; defines output voltage level by external voltage divider between Q, ADJ and GND.
2	Q	Output; Connect output pin to GND via a capacitor $C_Q \ge 10 \ \mu\text{F}$ with ESR $\le 20 \ \Omega$ (see also graph "Region of Stability").
3	I	Input
4 (TAB)	Q	Output; Connect to pin 2 and heatsink area on PCB



Parameter	Symbol	Lim	it Values	Unit	Test Condition
		Min.	Max.		
Input - Output Voltag	ge Differen	ce (varia	ble device	only)	
Voltage	$V_{\rm I}$ - $V_{\rm Q}$	-0.3	20	V	-
Input Voltage (fixed	voltage ve	rsion on	ly)		
Voltage	$V_{\rm I}$	-0.3	20	V	-
Output					
Voltage	V_{Q}	-0.3	20	V	-
Current	IQ	-	-	-	Internally limited
ESD Rating					
Electrostatic discharge voltage	$V_{\rm ESD}$	-2	2	kV	Human Body Mode
Temperature	- 1	-1			
Storage temperature	T _{stg}	-50	150	°C	-
Junction temperature	Ti	-40	150	°C	-

Table 3 Absolute Maximum Ratings

Note: Stresses above those listed here may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Table 4 Operating Range

Parameter	Symbol	Limit Values		Unit	Remarks
		Min.	Max.		
Input Voltage	V_1	$V_{\rm Q}$ + $V_{\rm DR}$	15	V	-
Junction temperature	Tj	0	125	°C	-

Table 5Thermal Resistance

Junction ambient	R _{thja}	-	164	K/W	PG-SOT223, footprint only.
		-	81	K/W	PG-SOT223, 300 mm ² heat sink area
Junction case	R _{thjc}	_	4	K/W	-

Note: In the operating range, the functions given in the circuit description are fulfilled.



Characteristics 3.3 V Fixed Output Voltage Device IFX1117ME V33

0 °C < $T_{\rm i}$ < **125** °C; $V_{\rm i}$ = 5 V, $I_{\rm O}$ = 10 mA; unless otherwise specified.

Parameter	Symbol Limi		nit Valı	/alues U		Measuring Conditions
		min.	typ.	max.	Ī	
Output voltage	V _Q	3.23 5	3.300	3.36 5	V	$0 \text{ mA} \le I_{\text{Q}} \le 800 \text{ mA} $ 4.7 V $\le V_{\text{I}} \le 10 \text{ V}$
Output voltage	V _Q	-	3.300	-	V	$0 \text{ mA} \le I_Q \le 1000 \text{ mA};$ 4.7 V $\le V_1 \le 15 \text{V}$
Line regulation	ΔV_{Q}	-	1	6	mV	$4.7 \text{ V} \le V_1 \le 15 \text{ V}$
Load regulation	ΔV_{Q}	-	1	10	mV	$0 \text{ mA} \le I_Q \le 800 \text{ mA};^{(1)}$
		-	2	_	mV	$0 \text{ mA} \le I_Q \le 1.0 \text{ A}^{1)}$
Drop voltage	V_{DR}	-	1.00	1.10	V	$I_{\rm Q} = 100 \ {\rm mA}^{2)}$
Drop voltage	V_{DR}	-	1.05	1.15	V	$I_{\rm Q} = 500 \ {\rm mA}^{2)}$
Drop voltage	V_{DR}	-	1.10	1.20	V	$I_{\rm Q} = 800 \ {\rm mA}^{2)}$
Drop voltage	V_{DR}	-	1.30	1.40	V	$I_{\rm Q} = 1.0 \ {\rm A}^{2)}$
$\overline{\text{Current consumption;}} \\ I_{q} = I_{I} - I_{Q}$	Iq	-	5	10	mA	<i>I</i> _Q = 10 mA
Temperature stability	ΔV_{Q}	-	16.5	-	mV	3)
Long Term Stability	-	-	0.3	-	%	3)
Current limit	I _{Qmax}	1100	-	2250	mA	$V_{\rm Q} = 0.5 {\rm V}$
RMS Output Noise	-	-	30	-	ppm	ppm of $V_{\rm Q}$, $T_{\rm j}$ = 25 °C 10 Hz \leq f \leq 10 kHz ³⁾
Power Supply Ripple Rejection	PSRR	60	65	-	dB	$f_{\rm r} = 120 \text{ Hz}, V_{\rm r} = 1 V_{\rm PP}^{3}$

1) Measured at constant junction temperature

2) Drop voltage measured when the output voltage has dropped 100 mV from the nominal value obtained at $V_{\rm I}$ = 5.0 V.

3) Specified by design; not subject to production test.



Characteristics Adjustable Output Voltage Device IFX1117ME V

0 °C < $T_{\rm i}$ < **125** °C; $V_{\rm l}$ = 5 V, $I_{\rm O}$ = 10 mA; unless otherwise specified.

Parameter	Symbol	Limit Values			Unit	Measuring Conditions
		min.	typ.	max.		
Reference voltage	V_Q	1.22 5	1.250	1.27 0	V	10 mA $\leq I_{Q} \leq$ 800 mA; 1.4 V $\leq (V_{I}-V_{Q}) \leq$ 10 V
Output voltage	V_Q	-	1.250	-	V	10 mA $\leq I_Q \leq$ 1000 mA; 2.65 V $\leq V_I \leq$ 15 V
Line regulation	ΔV_Q	-	0.035	0.2	% ¹⁾	1.5 V ≤(V _I -V _Q)≤ 13.75 V
Load regulation	ΔV_Q	-	0.2	0.4	% ¹⁾	$10 \text{ mA} \le I_Q \le 800 \text{ mA};^{2)}$
		-	0.25	_	% ¹⁾	10 mA \leq $I_{\rm Q}$ \leq 1.0 A $^{2)}$
Drop voltage	V_{DR}	-	1.00	1.10	V	$I_{\rm Q}$ = 100 mA ³⁾
Drop voltage	V_{DR}	-	1.05	1.15	V	$I_{\rm Q}$ = 500 mA ³⁾
Drop voltage	V_{DR}	-	1.10	1.20	V	$I_{\rm Q}$ = 800 mA ³⁾
Drop voltage	V_{DR}	-	1.30	1.40	V	$I_{\rm Q}$ = 1.0 A ³⁾
Minimum Load Current ⁴⁾	I_q	-	1.7	5.0	mA	<i>V</i> _I = 15 V
Adjust Current	I _{ADJ}	-	100	120	μA	$I_{\rm Q}$ = 10 mA
Adjust Current Change	ΔI_{ADJ}	-	2	5	μA	1.4 V $\leq (V_{\rm I} - V_{\rm Q}) \leq$ 13.6 V; 10 mA $\leq I_{\rm Q} \leq$ 800 mA
Temperature stability	ΔV_Q	-	0.5	-	% ¹⁾	5)
Long Term Stability	-	-	0.3	-	% ¹⁾	5)
Current limit	I _{Qmax}	1100	-	2250	mA	$V_{\rm Q} = 0.5 \ {\rm V}$
RMS Output Noise	-	-	30	-	ppm	ppm of $V_{\rm Q}$, $T_{\rm j}$ = 25 °C 10 Hz \leq f \leq 10 kHz $^{5)}$
Power Supply Ripple Rejection	PSRR	65	70	-	dB	$f_{\rm r}$ = 120 Hz, $V_{\rm r}$ = 1 V _{PP} ⁵⁾

1) Related to V_Q

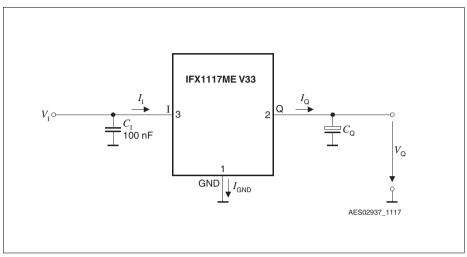
2) Measured at constant junction temperature

3) Drop voltage measured when the output voltage has dropped 100 mV from the nominal value obtained at $\mathit{V}_{\rm I}$ = 5.0 V.

4) Minimum load current required to maintain regulation

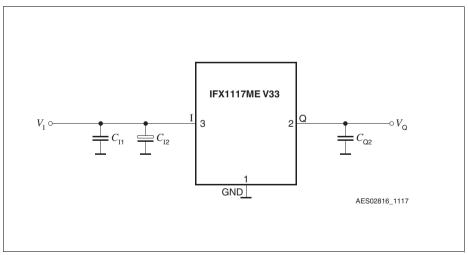
5) Specified by design; not subject to production test.

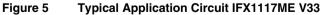






Application Information







Output

The IFX1117 requires a 10 μ F output capacitor with ESR \leq 20 Ω for the stability of the regulation loop. The use of a tantalum output capacitor is recommended.

For the adjustable device IFX1117ME V the output voltage level can be defined by a voltage divider between Q, ADJ and GND.

The output voltage calculates:

$$V_{\rm Q} = V_{\rm REF} \times \left(1 + \frac{R_2}{R_1}\right) + I_{\rm ADJ} \times R_2 \tag{1}$$

At the input of the regulator a capacitor is recommended to compensate line influences. As a minimum a 100 nF ceramic input capacitor should be used. If the regulator is used in an environment with long input lines an input capacitance of 10 μ F is suggested.

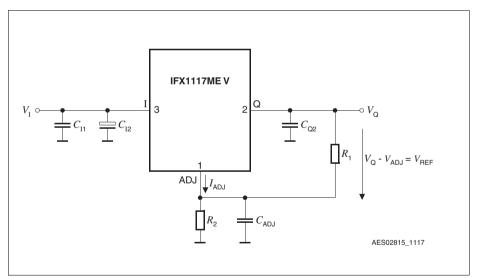
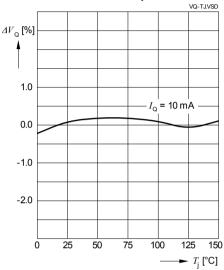


Figure 6 Typical Application Circuit IFX1117ME V

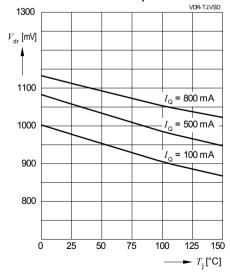


Typical Performance Characteristics

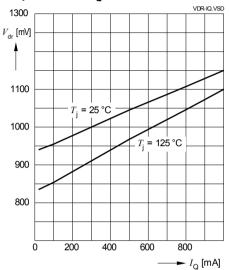




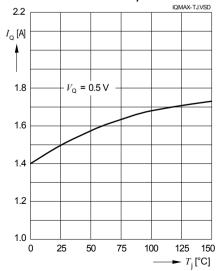
Dropout Voltage V_{dr} versus Junction Temperature T_{i}



Dropout Voltage V_{dr} versus Output Current I_{O}



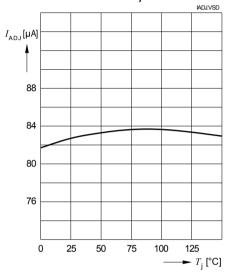
Maximum Output Current I_{Q} versus Junction Temperature T_{i}



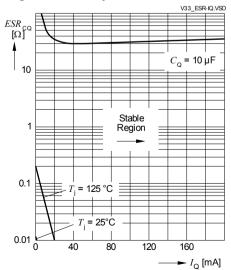


Typical Performance Characteristics

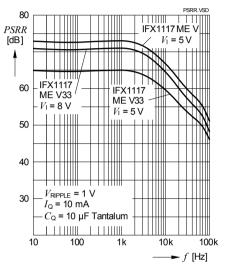
Adjust Pin Current I_{ADJ} versus Junction Temperature T_i



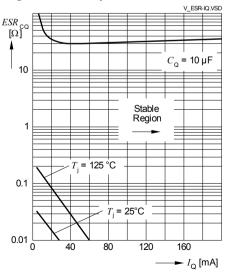
Region of Stability Version ME V33



Power Supply Ripple Rejection PSRR versus Frequency f



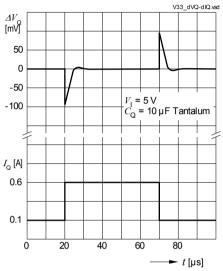
Region of Stability Version ME V



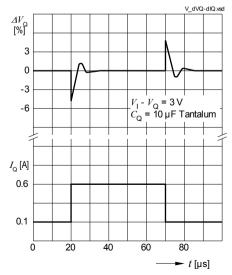


Typical Performance Characteristics

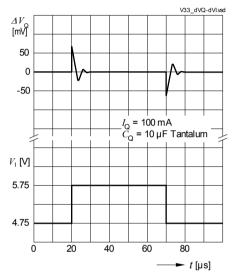
Load Transient Response Version ME V33



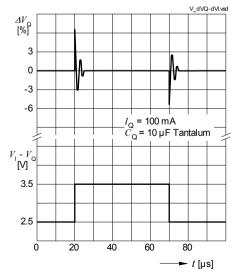
Load Transient Response Version ME V



Line Transient Response Version ME V33



Line Transient Response Version ME V





Package Outline

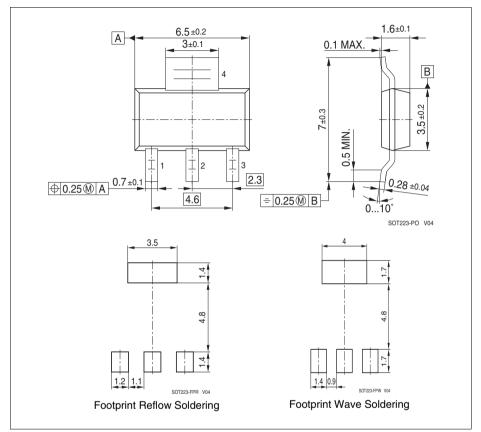


Figure 7 Outline and footprint PG-SOT223

Green Product (RoHS-Compliant)

To meet the world-wide customer requirements for environmentally friendly products and to be compliant with government regulations the device is available as a green product. Green products are RoHS-Compliant (i.e Pb-free finish on leads and suitable for Pb-free soldering according to IPC/JEDEC J-STD-020).

You can find all of our packages, sorts of packing and others in our Infineon Internet Page "Products": http://www.infineon.com/products.

SMD = Surface Mounted Device

Dimensions in mm





Revision History

Version	Date	Changes
Rev. 1.0	2011-02-24	Data Sheet

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